HIGH-VOLTAGE ANALOG-SIGNAL IC

UC5707
2-channel Constant Current Regulator
RoHS compliant Green Product

Preliminary Specifications Datasheet Revision: 0.2

IC Version: c_A March 13, 2013



UC5707

2-channel Constant Current Regulator

INTRODUCTION

The UC5707 is a 2-channel LED driver, designed for current regulation. It may be used in various current regulation circuits, especially suitable for LED applications. It lets LEDs work under stable current and avoid brightness unstable caused by current change, while its low voltage can reduce power consumption.

The connection of the V_{DD} power pin may also be used for brightness control of LEDs via PWM signals; therefore suitable for applications that need brightness adjustment.

The connection of R_{EXT} pin can be used for the control of output current, to control and drive more LEDs. When R_{EXT} is open, VCH1, VCH2 pins may provide 30mA of current. To achieve operations with VCH1/VCH2 current over 60mA, connect the ICs in parallel.

MAIN APPLICATIONS

 LED Light Bars, LED Bulbs, LED Fluorescent Lights, LED Backlight

FEATURE HIGHLIGHTS

- Wide operation supply voltage range: 2.5V ~ 40V
- Wide output voltage range: 2.5V~40V
- 15mA to 60mA /per channel sink current
- Accurate sink current: ± 5%
- VDD pin as OE function: up to 100KHz frequency
- Negative temperature coefficient: ± 500ppm/°C
- Less than ±0.5%/V load regulation
- -40 °C ~+85 °C operation temperature range
- High temperature protection: 95 °C ~ 155°C
- Pb-free and green package: SOT89-5, SOT23-5

BLOCK DIAGRAM



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ORDERING INFORMATION

Part Number	I ² C	Package	Eco	Description
UC5707cA-UST8905R7	No	SOT89-5	RoHS compliant	Pb-free
UC5707cA-UST2305R7	No	SOT23-5	RoHS compliant	Pb-free

General Notes

APPLICATION INFORMATION

For improved readability, the specification contains many application data points. When application information is given, it is advisory and does not form part of the specification for the device.

BARE DIE DISCLAIMER

All die are tested and are guaranteed to comply with all data sheet limits up to the point of wafer sawing. There is no post waffle saw/pack testing performed on individual die. Although the latest modern processes are utilized for wafer sawing and die pick-&-place into waffle pack carriers, UltraChip has no control of third party procedures in the handling, packing or assembly of the die. Accordingly, it is the responsibility of the customer to test and qualify their application in which the die is to be used. UltraChip assumes no liability for device functionality or performance of the die or systems after handling, packing or assembly of the die.

LIFE SUPPORT APPLICATIONS

These devices are not designed for use in life support appliances, or systems where malfunction of these products can reasonably be expected to result in personal injuries. Customer using or selling these products for use in such applications do so at their own risk.

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PIN DESCRIPTION



SOT89-5

5 VDD 4REXT UC5707 2 GND 3 VcH2 1 VcH1

SOT23-5

SOT89-5

No	Pin	Туре	Description
1	Vсн1	PWR	Current driver output.
2	GND	GND	Ground
3	Vсн2	PWR	Current driver output.
4	R _{EXT}	1	Connect a resistor to Ground for adjusting current
5	Vdd	PWR	Input supply voltage.
Thermal Pad	GND	GND	Ground
SOT23-5			

No	Pin	Туре	Description
1	Vсн1	PWR	Current driver output.
2	GND	GND	Ground
3	Vсн2	PWR	Current driver output.
4	R _{EXT}		Connect a resistor to Ground for adjusting current
5	Vdd	PWR	Input Supply voltage

MAXIMUM RATING

Symbol	Parameter	Range	Unit
Vdd	Supply Voltage	44	V
V (сн1, сн2)	Current Regulator Output Voltage	44	V
I (сн1, сн2)	Current Regulator Output Current	65	mA
I (GND)	Output Saturation Current	132	mA
TJ	Junction Temperature	7 150	°C
Тѕтс	Storage Temperature	-40 ~ +125	°C
R _{тн} (j-а)	Thermal Resistance (junction to ambient) SOT89-5	150	°C/W
R _{тн} (j-с)	Thermal Resistance (junction to case) SOT89-5	50	°C/W
Pt-sot89-5	Power Dissipation (SOT89-5) [Note]	1000	mW
R _{тн} (j-а)	Thermal Resistance (junction to ambient) SOT23-5	215	°C/W
R _{тн} (j-с)	Thermal Resistance (junction to case) SOT23-5	50	°C/W
Pt-sot23-5	Power dissipation (SOT23-5), Ta=25 °C	550	mW

Note:

Conditions for Power Dissipation (SOT89-5) :

Double-side FR4, PCB Size 50mmx50mmx1.6mm, Copper Ratio approx. 10% for top side and approx. 100% for back side, No through-holes, and Ta=25°C.

DC CHARACTERISTICS

V0 2-00V	Vсн1 Vсн2-1 0V	Cvpp – 0.1uF	C1 - C2 - 10 nE	T₄−25°C:	unless otherwise specified
vDD=3.0v,	VCHI, VCHZ=1.0V,	$\mathbf{C}\mathbf{V}\mathbf{D}\mathbf{D}=0.\mathbf{T}\mathbf{u}\mathbf{F},$	CI=CZ=IUIIF,	IA=25C	uniess otherwise specified.

Symbol	Characteristics	Condition	Min.	Typical	Max.	Unit
V _{DD}	Supply Voltage		2.5	-	40	V
	Output Voltage (20mA)	V _{DD} >5V, ICH1 or ICH2= 30mA	0.4	-	40	V
	Output Voltage (SomA)	V _{DD} =2.5V, ICн1 or ICн2= 30mA	0.7	-	40	V
VCHT, VCHZ		V _{DD} >5V, ICH1 or ICH2= 60mA	0.8		40	V
		V _{DD} =3V, ICH1 or ICH2= 60mA	1	-	40	V
I _{DD}	Supply Current		-	400	600	uA
Існ1, Існ2	Peak Regulated Current		30	-	60	mA
IAC	Output Current Accuracy	V _{DD} =3.0V, Vсн1 or Vсн2=1.0V	-5	-	+5	%
tcoe	Temperature Coefficient	Tj=–40 °C ~125 °C	-500	-	+500	ppm/°C
R _{EXT}	External Resistor		11250	-	Open	Ω
%/V _{DD}	Line Regulation	V _{DD} =2.5V~40V, VCH1 or VCH2=2.5V	-0.5	-	+0.5	%/V
%/Vсн	Load Regulation	V _{DD} =3.0V, Vсн1 or Vсн2=2.5V~40V	-0.5	-	+0.5	%/V
totp	OTP Active Temperature	V _{DD} =2.5V~40V	-	155	_	°C
tOPT_IN	OTP Inactive Temperature	V _{DD} =2.5V~40V	_	95	_	°C

Note: The condition can be achieved with the test circuit only.

TEST CIRCUIT



$$I_{VCH(REXT)} = (1 + \frac{R_{IN}}{R_{EXT}}) \bullet I_{VCH(open)}$$

where RIN=11250 $\Omega,$ and I_VCH is reference current with REXT open.

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VDD TIMING



Ta=25°C, ICH=0mA~30mA

Symbol	Parameter	Condition	Min.	Typical	Max.	Unit
tRISE	ICH Current Rise, V_{DD} Rise	V _{CH} =1V, V _{DD} =0V to 3V, ICH=0mA to 30mA	-	3	5	uS
t PLH	ICH Current Rise, V _{DD} Rise	V _{CH} =1V, V _{DD} =0V to 3V, ICH=0mA to 30mA	-	3	5	uS
tFALL	ICH Current Fall, VDD Fall	$V_{CH}=1V$, $V_{DD}=3V$ to 0V, ICH=30mA to 0mA	-	0.5	1	uS
t PHL	Існ Current Fall, V _{DD} Fall	$V_{CH}=1V$, $V_{DD}=3V$ to 0V, ICH=30mA to 0mA	-	0.5	1	uS
Ta=25°C,	Існ=0mA~60mA					

Ta=25°C, ICH=0mA~60mA

Symbol	Parameter	Condition	Min.	Typical	Max.	Unit
trise	ICH Current Rise, VDD Rise	V_{CH} =1.5V, V_{DD} =0V to 5V, ICH=0mA to 60mA	Ι	4	7	uS
t PLH	ICH Current Rise, VDD Rise	$V_{CH}=1.5V, V_{DD}=0V$ to 5V, ICH=0mA to 60mA	Ι	4	7	uS
tFALL	ICH Current Fall, VDD Fall	V_{CH} =1.5V, V_{DD} =5V to 0V, ICH=60mA to 0mA	-	0.5	1	uS
t PHL	Iсн Current Fall, V _{DD} Fall	V _{CH} =1.5V, V _{DD} =5V to 0V, ICH=60mA to 0mA	-	0.5	1	uS
	GO					

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TEMPERATURE PROTECTION



Temperature Protection

VDD=2.5~40V

Protection	Typical	Unit
Active	155	°C
Inactive	95	°C

Note: The temperature detection is for the chip; not for ambience.

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APPLICATION SCHEMATIC



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PACKAGE INFORMATION

SOT89-5

	Dimension (Unit: mm)		Dimension	(Unit: inch)
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.360	0.560	0.014	0.022
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.400	1.800	0.055	0.071
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500) Тур.	0.060	Э Тур.
e1	2.900	3.100	0.114	0.122
L	0.900	1.100	0.035	0.043





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SOT23-5

Dimension	Unit: mm			Dimension	Unit: mm			
	Min.	Normal	Max.		Min.	Normal	Max.	
А	-	0.95BSC	-	F	0.00	-	0.10	
A1	-	1.9BSC	-	G	0.30	0.40	0.50	
В	2.60	2.80	3.00	Н	0.10	0.15	0.20	
С	1.40	1.50	1.70	I	0.30	-	0.60	
D	2.80	2.90	3.10	J	5*	_	10*	
E	1.00	1.10	1.20*	_	-	_	_	





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